

DDC (LO-R1) U

NPN PRE-BIASED SMALL SIGNAL SOT-363 DUAL SURFACE MOUNT TRANSISTOR

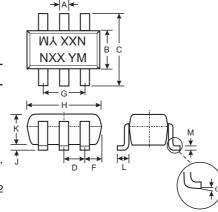
Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDA)
- Built-In Biasing Resistors
- Lead Free/RoHS Compliant (Note 3)

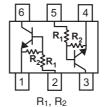
Mechanical Data

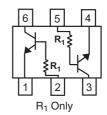
- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe)
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 2)
- Ordering Information (See Page 2)
- Weight: 0.006 grams (approximate)

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDC122LU	0.22K	10K	N81
DDC142JU	0.47K	10K	N82
DDC122TU	0.22K	OPEN	N83
DDC142TU	0.47K	OPEN	N84



	SOT-363						
Dim	Min	Max					
Α	0.10	0.30					
В	1.15	1.35					
С	2.00 2.20						
D	0.65 Nominal						
F	0.30	0.40					
Н	1.80	2.20					
J	_	0.10					
K	0.90	1.00					
L	0.25	0.40					
M	0.10	0.25					
α	0°	8°					
All Din	nensions	in mm					





SCHEMATIC DIAGRAM

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Supply Voltage (6) to (1) and (3) to (4)		V _{CC}	50	V
nput Voltage (2) to (1) and (5) to (4) DDC122LU DDC142JU		V _{IN}	-5 to +6 -5 to +6	V
Input Voltage (1) to (2) and (4) to (5)	DDC122TU DDC142TU	V _{EBO (MAX)}	5	V
Output Current	All	Ic	100	mA
Power Dissipation (Note 1)		Pd	200	mW
Thermal Resistance, Junction to Ambient A	ir (Note 1)	R _{θJA}	625	°C/W

Note: 1. 150mW per element must not be exceeded.

- 2. Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.
- 3. No purposefully added lead.



Electrical Characteristics @ T_A = 25°C unless otherwise specified R1, R2 Types

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Input Voltage	DDC122LU DDC142JU	$V_{l(off)} \\$	0.3 0.3		_	V	$V_{CC}=5V,\ I_O=100\mu A$
	DDC122LU DDC142JU	V _{I(on)}	_	_	2.0 2.0	٧	V _O = 0.3V, I _O = 20mA V _O = 0.3V, I _O = 20mA
Output Voltage	V _{O(on)}	_		0.3V	V	$I_O/I_I = 5\text{mA}/0.25\text{mA}$	
Input Current DDC122LU DDC142JU		II	_	_	28 13	mA	V _I = 5V
Output Current	Output Current		_	_	0.5	μΑ	$V_{CC} = 50V, V_I = 0V$
DC Current Gain DDC122LU DDC142JU		Gı	56 56	_	_	_	V _O = 5V, I _O = 10mA
Gain-Bandwidth Product*		f⊤	_	200	_	MHz	$V_{CE} = 10V$, $I_E = 5mA$, $f = 100MHz$

^{*} Transistor - For Reference Only

Electrical Characteristics @ T_A = 25°C unless otherwise specified R1-Only

Characteristic	Characteristic				Max	Unit	Test Condition
Collector-Base Breakdown Voltag	BV _{CBO}	50	_	_	V	$I_C = 50\mu A$	
Collector-Emitter Breakdown Volt	age	BV _{CEO}	40	_	_	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	5	_	_	V	$I_E = 50\mu A$ $I_E = 50\mu A$	
Collector Cutoff Current	I _{CBO}	_	_	0.5	μΑ	$V_{CB} = 50V$	
Emitter Cutoff Current DDC122TU DDC142TU		I _{EBO}	_	_	0.5 0.5	μА	V _{EB} = 4V
Collector-Emitter Saturation Volta	ge	V _{CE(sat)}	_	_	0.3	V	$I_C = 5mA, I_B = 0.25mA$
DC Current Transfer Ratio DDC122TU DDC142TU		h _{FE}	100 100	250 250	600 600	_	$I_C = 1$ mA, $V_{CE} = 5$ V
Gain-Bandwidth Product*	f⊤	_	200	_	MHz	$V_{CE} = 10V, I_E = -5mA, f = 100MHz$	

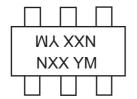
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Ordering Information (Note 4)

Device	Packaging	Shipping
DDC122LU-7-F	SOT-363	3000/Tape & Reel
DDC142JU-7-F	SOT-363	3000/Tape & Reel
DDC122TU-7-F	SOT-363	3000/Tape & Reel
DDC142TU-7-F	SOT-363	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



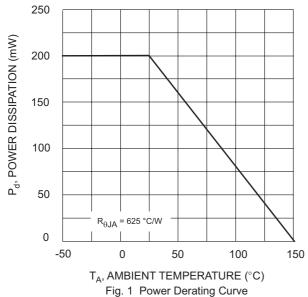
NXX = Product Type Marking Code See Sheet 1 Diagrams YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	N	Р	R	S	Т	U	V	W	Х	Υ	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D





(150mW per element must not be exceeded).

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